

isc N-Channel MOSFET Transistor

IRFP4127, IIRFP4127

• FEATURES

- Static drain-source on-resistance:
 $R_{DS(on)} \leq 21m\Omega$
- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

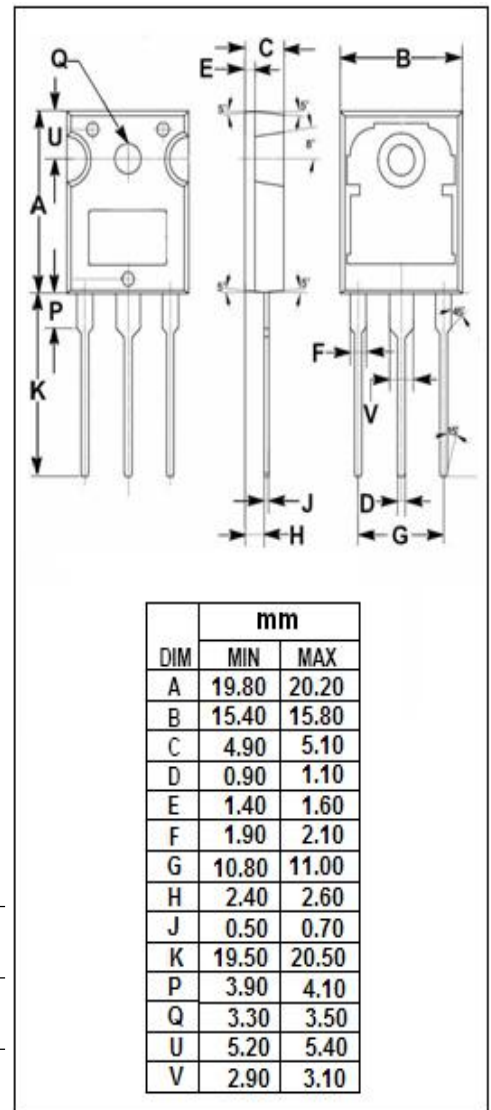
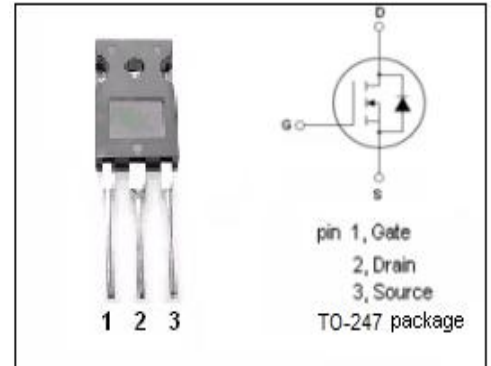
- High Efficiency Synchronous Rectification in SMPS
- Uninterruptible Power Supply
- High Speed Power Switching
- Hard Switched And High Frequency Circuits

• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	200	V
V _{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous	75	A
I _{DM}	Drain Current-Single Pulsed	300	A
P _D	Total Dissipation @T _c =25°C	341	W
T _j	Max. Operating Junction Temperature	175	°C
T _{stg}	Storage Temperature	-55~175	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th(j-c)}	Channel-to-case thermal resistance	0.4	°C/W
R _{th(j-a)}	Channel-to-ambient thermal resistance	40	°C/W



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ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =250 μ A	200			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =250 μ A	3.0		5.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =44A			21	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V			±0.1	μ A
I _{DSS}	Drain-Source Leakage Current	V _{DS} =200V; V _{GS} = 0V			20	μ A
V _{SD}	Diode forward voltage	I _S =44A, V _{GS} = 0V			1.3	V

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